

Supporting Information

Transition Metal Si-Chalcogenides: A New Two-Dimensional Anode Material for Na-Ion Batteries

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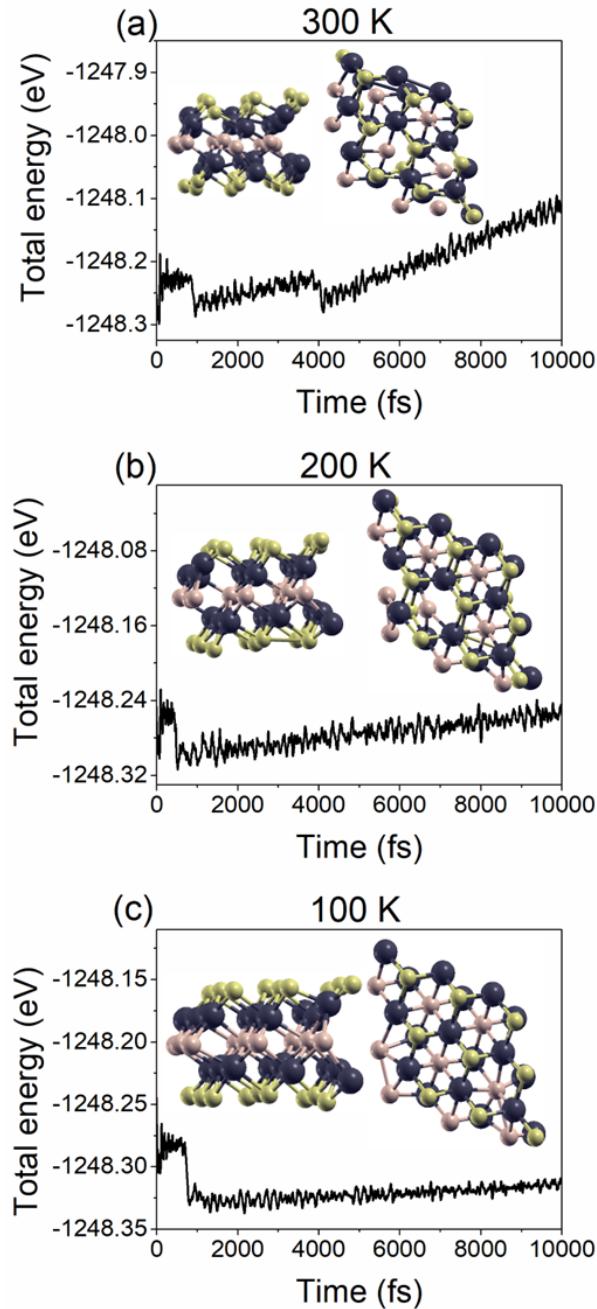


Fig. S1 Fluctuation of energy under AIMD simulations at (a) 300 K (b) 200 K and (c) 100 K for 2D Nb₂S₂Si. The yellow, black and light pink balls denote S, Nb and Si atoms, respectively.

2D Ta₂Se₂Si (C_{Ta-Si})

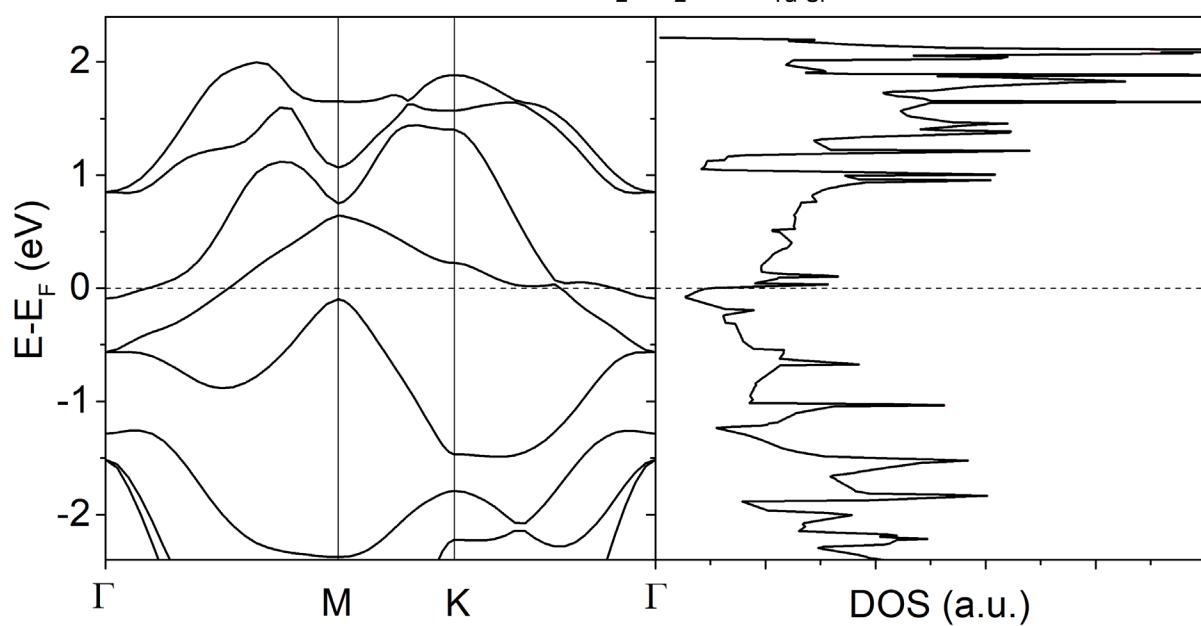


Fig. S2 Band structure and DOS of the 2D T₂Se₂Si (C_{Ta-Si}).